Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

8.185 inches

Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

**Mounting Method:** 

Threaded stud

**Features Provided:** 

Hermetically sealed case

**Overall Width Across Flats:** 

Between 1.049 inches and 1.750 inches

**Thread Size:** 

0.500 inches

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

750.0 repetitive peak off-state voltage

## **Current Rating Per Characteristic:**

110.00 amperes source cutoff current preset and 1200.00 amperes forward current, total rms watts

## Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector blank

### Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: pnpn

### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

3 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

### Unit Of Measure:

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Demilitarization:

No

Fiig:

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